08.2-09 CRYSTAL STRUCTURE OF PRECURSOR TO FLUORIDE-SILICALITE. By J. J. Pluth, G. D. Price and J. V. Smith, Dept. of the Geophysical Sciences, University of Chicago, Chicago, IL 60637, USA and J. M. Bennett, Union Carbide Corporation, Tarrytown, New York, NY 10591, USA.

The crystal structure of a tetrapropylammonium (TPA) fluoride containing precursor to fluoride silicalite, a new microporous crystalline silica polymorph (Flanigen et al. U. S. Patent NM. 4,073,865, Feb. 14, 1978) similar in some properties to silicalite, is reported.

The strycture of the precursor (a=20.04, b=19.92, c=13.39Å) was determined for interpenetrant twins on (110) with optically monoclinic symmetry and pseudo space-group Pnma, first to R=0.10 for the silica framework and then to R=0.05 after location of the tetrapropylammonium fluoride complex. The intensities of 8000 X-ray diffractions did not deviate significantly from orthorhombic symmetry, and full account was taken in the refinement of the twinning.

A tetrahedral silica framework with Si-O distances ranging from 1.55 to 1.65Å was found with topology like that reported for silicalite (Flanigen et al., Nature $\underline{271}$, 512-516, 1978) and characterized by intersecting channels defined by ten-rings.

The nitrogen atom of each TPA complex lies at the near-tetrahedral intersection of a straight and a zig-zag channel, and a propyl limb projects along each channel to approach a propyl limb from the next TPA complex. The neat fit between the silica framework and the TPA complex is consistent with a template mechanism for crystallization.

NSF CHE 78-26579

08.2-10 THE CRYSTAL STRUCTURE OF SIALON X-D-HASE. By P. Korgul, D.P. Thompson and K.H. Jack, Wolfson Research Group for High-Strength Materials, Crystallography Laboratory, University of Newcastle upon Tyne, England.

X-phase is a silicon aluminium oxynitride of approximate composition Si_Al_0_12^N_2 which occurs in two crystalline forms, high and $16^{\rm w}_{1.2}^{\rm N}_{2.2}^{\rm N}_{2.2}^{$

08.2-11 RE-INVESTIGATION OF THE STRUCTURE OF $\mathsf{Si}_3\mathsf{O}_3(\mathsf{CH}_3)_6$ AT -165°C. By R. Pomés, Yu.I. Smolin and Yu.F. Shepelev, Department of X-ray, Faculty of Physics, University of Oriente, Santiago de Cuba, Cuba; and Institute of Silicate Chemistry, Academy of Sciences of the USSR, Leningrad, USSR.

The crystal structure of $$\rm Si_3O_3(CH_3)_6$$ has been redetermined and refined by least-squares calculations using X-ray counter data, and with anisotropic thermal parameters for the non-hydrogen atoms. The space group is R3m and the cell parameters from diffractometer data are ~a=4.445 and c=18.74 Å. The

The space group is R3m and the cell parameters from diffractometer data are a = 4.445 and c = 18.74 Å. The intensity data were measured on a manual single-crystal diffractometer using Mo(K α) radiation and a low-temperature attachment. The initial parameters for the refinement were those reported by G. Peyronel (Atti. Acad. Naz. Lic. Rend. ce Sci. Fis. Mat. 15, 402 (1953); 16, 78, 231 (1954)). The final R index is 0.10.

From our results, we are able to conclude that the molecule of $\mathrm{Si}_3\mathrm{O}_3(\mathrm{CH}_3)_6$ is not planar as reported by Peyronel. The silicon and oxygen atoms have been located on different levels with a separation of 0.19 Å between them.

Despite the utilization of low temperature, we observed very strong thermal oscillations, and it was necessary to correct the interatomic distances for thermal motion.

08.2--12 HIGH PRESSURE SYNTHESIS AND CRYSTAL STRUCTURES OF MODIFIED VANADIUM HOLLANDITES $\text{A}_{2-x}\text{V}_{8+2x}\text{O}_{16+x}$ (A = K, Rb). By K.-J. Range, W. Abriel and C. Garbe, Institut für Anorganische Chemie, Universität Regensburg, Regensburg, Bundesrepublik Deutschland.

The title compounds were synthesized by high pressure – high temperature treatment of KVO3 and RbVO3 in a modified belt-type apparatus. They crystallize in monoclinic space group 1112/m with lattice constants a = 10.979(3) Å, b = 9.383(3) Å, c = 2.922(1) Å, γ = 92.26° (A = K, x = 1.22); a = 10.979(3) Å, b = 9.383(3) Å, c = 2.902(2) Å, γ = 92.26° (A = K, x = 1.08); a = 10.895(3) Å, b = 9.385(3) Å, c = 2.909(2) Å, γ = 92.25° (A = Rb, x = 1.1). The crystal structures were determined from single crystal data and refined to an R of 0.068, 0.074 and 0.061 for the three compounds. In contrast to the normal vanadium hollandites $A_{2-x}V_{8}O_{16}$ (Range et al., Mat.Res.Bull. (1979) 14, 1463) the large alkali ions alternate randomly with V-O-V groups in the "tunnel" sites, building additional VO6 octahedra and completing a nearly close packed oxygen lattice (layer sequence ABAC...). An ordered variant of $K_{2-x}V_{8+2}xO_{16+x}$ was synthesized from KVO3 at 3 kbars and 900° C in a gold capsule. The unit cell is monoclinic, space group B112/m, with a = 21.96(2) Å, b = 9.383(3) Å, c = 5.935(2)Å, γ = 92.26°, and contains 4 (K0.9V10.2O17.1). The crystal structure (1249 unique reflections, R = 0.065) shows a pronounced separation of K+ and V-O-V groups in different tunnels. A geometrical analysis of the V3+/V4+ distribution, based on the different distortions of the VO6 octahedra, is given.